

**Micro Commercial Components** 

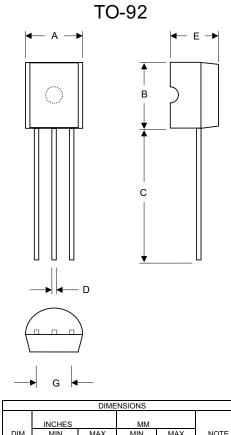
Micro Commercial Components 20736 Marilla Street Chatsworth CA 91311

Phone: (818) 701-4933 (818) 701-4939 S8550-B S8550-C S8550-D

# **Features**

- TO-92 Plastic-Encapsulate Transistors
- Capable of 0.625Watts(Tamb=25°C) of Power Dissipation.
- Collector-current 0.5A
- Collector-base Voltage 40V
- Operating and storage junction temperature range: -55°C to +150°C
- Marking: S8550
- Lead Free Finish/RoHS Compliant ("P" Suffix designates RoHS Compliant. See ordering information)
- Case Material: Molded Plastic. UL Flammability Classification Rating 94V-0 and MSL Rating 1

# **PNP Silicon Transistors**



C   DIMENSIONS   DIMENSIONS	
DIMENSIONS   INCHES   MM   MAX   A   .170   .190   4.33   4.83	
C	
INCHES   MM   MAX   MIN   MAX   A   .170   .190   4.33   4.83	
DIM   MIN   MAX   MIN   MAX   A   .170   .190   4.33   4.83	1
A .170 .190 4.33 4.83	
B .170 .190 4.30 4.83	H
C 550 500 13.07 14.07	
0 .550 .590 15.97 14.97	

DIMENSIONS					
	INCHES		MM		
DIM	MIN	MAX	MIN	MAX	NOTE
Α	.170	.190	4.33	4.83	
В	.170	.190	4.30	4.83	
С	.550	.590	13.97	14.97	
D	.010	.020	0.36	0.56	
Е	.130	.160	3.30	3.96	
G	.010	.104	2.44	2.64	

Symbol	Parameter	Min	Max	Units	
OFF CHARAC	OFF CHARACTERISTICS				
$V_{(BR)CBO}$	Collector-Base Breakdown Voltage (	40		Vdc	
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage (\(\beta=0.1\text{mAdc}, \lambda_0=0\)	25	-	Vdc	
$V_{(BR)EBO}$	Emitter-Base Breakdown Voltage (£=100uAdc, l <sub>C</sub> =0)	5.0	I	Vdc	
Сво	Collector Cutoff Current (V <sub>CB</sub> =40Vdc, $\xi$ =0)		0.1	uAdc	
CEO	Collector Cutoff Current (V <sub>CE</sub> =20Vdc, $\S$ =0)		0.2	uAdc	
I <sub>EBO</sub>	Emitter Cutoff Current $(V_{EB}=3.0Vdc, \xi=0)$		0.1	uAdc	

# **ON CHARACTERISTICS**

h <sub>FE(1)</sub>	DC Current Gain	85	300	
	( $l_c$ =50mAdc, $V_{CE}$ =1.0Vdc)			
h <sub>FE(2)</sub>	DC Current Gain	40		
. ,	(b=500mAdc, V <sub>CE</sub> =1.0Vdc)			
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage		0.6	Vdc
	(b=500mAdc, b=50mAdc)			
$V_{BE(sat)}$	Base-Emitter Saturation Voltage		1.2	Vdc
. ,	(l <sub>c</sub> =500mAdc, l <sub>s</sub> =50mAdc)			
$V_{EB}$	Base- Emitter Voltage		1.4	Vdc
	(I <sub>E</sub> =100mAdc)			

# **SMALL-SIGNAL CHARACTERISTICS**

f⊤	Transistor Frequency	150	 MHz
	( $l_c$ =20mAdc, $V_{ce}$ =6.0Vdc, f=30MHz)		

### **CLASSIFICATION OF HEED**

Rank	В	С	D
Range	85-150	120-200	160-300

www.mccsemi.com.

1 of 2



# **Ordering Information**

Device	Packing
(Part Number)-AP	Tape&Reel2Kpcs/Box
(Part Number)-BP	Bulk;1Kpcs/Bag

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